

isc N-Channel MOSFET Transistor

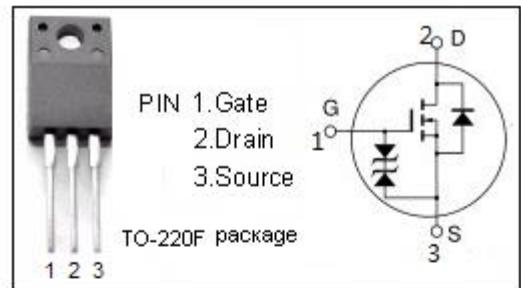
2SK2352

DESCRIPTION

- Drain Current $I_D = 6A @ T_C=25^\circ\text{C}$
- Drain Source Voltage-
: $V_{DSS} = 600\text{V}(\text{Min})$
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

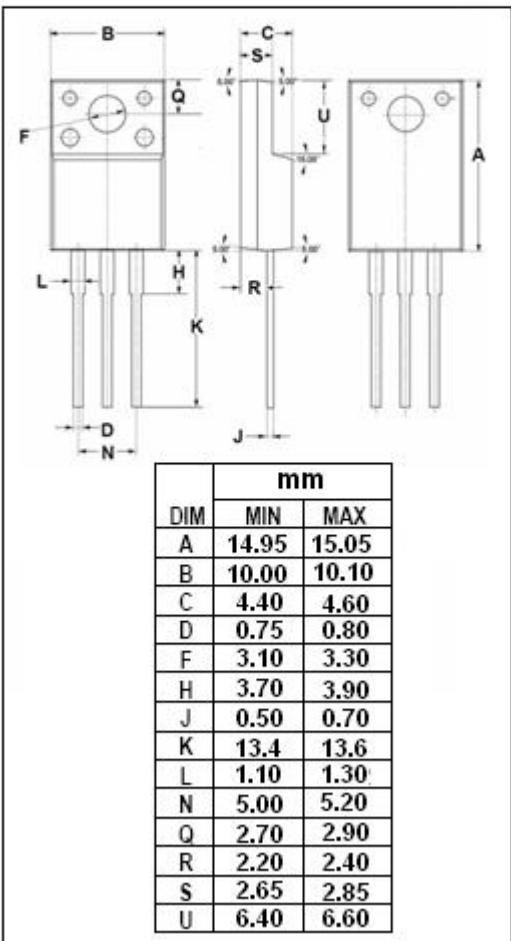
- Switching Regulators
- DC-DC Converter,
- Motor Control

**ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)**

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage ($V_{GS}=0$)	600	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-continuous@ $T_C=25^\circ\text{C}$	6	A
$I_{D(\text{puls})}$	Pulsed Drain Current	24	A
P_{tot}	Total Dissipation@ $T_C=25^\circ\text{C}$	45	W
T_j	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{\text{th j-c}}$	Thermal Resistance, Junction to Case	1.25	$^\circ\text{C/W}$
$R_{\text{th j-a}}$	Thermal Resistance, Junction to Ambient	83.3	$^\circ\text{C/W}$



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• ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0$; $I_D=10\text{mA}$	600			V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=10\text{V}$; $I_D=1\text{mA}$	2.0		4.0	V
V_{SD}	Diode Forward On-Voltage	$I_S=6\text{A}$; $V_{\text{GS}}=0$			1.8	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$V_{\text{GS}}=10\text{V}$; $I_D=3\text{A}$		1.06	1.25	Ω
I_{GSS}	Gate-Body Leakage Current	$V_{\text{GS}}= \pm 25\text{V}$; $V_{\text{DS}}=0$			± 10	μA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}}=600\text{V}$; $V_{\text{GS}}=0$			100	μA
C_{iss}	Input Capacitance	$V_{\text{DS}}=10\text{V}$; $V_{\text{GS}}=0\text{V}$; $f_T=1\text{MHz}$		1250		pF
C_{rss}	Reverse Transfer Capacitance			75		
C_{oss}	Output Capacitance			320		
t_r	Rise Time	$V_{\text{GS}}=10\text{V}$; $I_D=3\text{A}$; $V_{\text{DD}}=300\text{V}$; $R_L=100\ \Omega$		14		ns
t_{on}	Turn-on Time			35		
t_f	Fall Time			12		
t_{off}	Turn-off Time			65		

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